

MMST4401

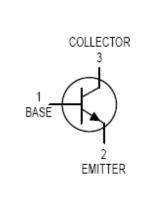
NPN General Purpose Transistor

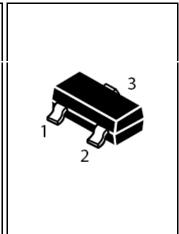
FEATURES

- Ideal for Medium Power Amplification and Switching
- Complementary PNP Type available(MMST4403)

MECHANICAL DATA

- Case: SOT-323 Plastic
- Case material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Lead Free in RoHS 2002/95/EC Compliant





Maximum Ratings @ $T_A = 25^{\circ}C$

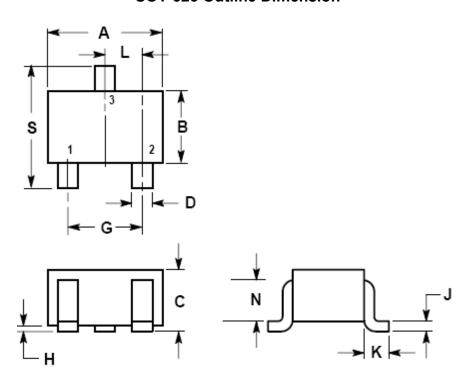
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current -Continuous	I _C	600	mA
Total Power Dissipation FR-4 board	P_{D}	150	mW
Junction Temperature	T_J	150	$^{\circ}\!\mathbb{C}$
Storage Temperature Range	T _{STG}	-55~+150	$^{\circ}\!\mathbb{C}$

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	I _C =100μA,I _E =0	V _{CBO}	60			V
Collector-emitter breakdown voltage	I _C =1mA,I _B =0	V _{CEO}	40			V
Emitter-base breakdown voltage	I _E =100μA,I _C =0	V _{EBO}	6			V
Collector-emitter cut-off current	V _{CE} =35V,V _{BE(off)} =0.4V	I _{CEX}			0.1	uA
DC current gain	V _{CE} =1V,I _C =0.1mA	h _{FE1}	20			
	V _{CE} =1V,I _C =1mA	h _{FE2}	40			
	V _{CE} =1V,I _C =10mA	h _{FE3}	80			
	V _{CE} =1V,I _C =150mA	h _{FE4}	100		300	
	V _{CE} =2V,I _C =500mA	h _{FE5}	40			
Collector-emitter saturation voltage	I _C =150mA,I _B =15mA	V _{CE} (sat)1			0.4	V
	I _C =500mA,I _B =50mA	V _{CE} (sat)2			0.75	V
Base-emitter saturation voltage	I _C =150mA,I _B =15mA	V _{BE} (sat)1	0.75		0.95	V
	I_C =500mA, I_B =50mA	V _{BE} (sat)2			1.20	V
Transition frequency	V _{CE} =10V,I _C =20mA, f=100MHz	f_{T}	250			MHz
Output Capacitance	V_{CB} =5 V , I_E =0, f =1 MHz	Cob			6.5	pF
Delay time	V _{CC} =30V, V _{BE(off)} =2V	T _d			15	nS
Rise time	I _C =150mA , I _{B1} = 15mA	T _r			20	nS
Storage time	V _{CC} =30 V, I _C =150mA I _{B1} =-I _{B2} =15mA	T _s			225	nS
Fall time		T _f			30	nS

REV.0, Jan-2013, KSNR22

SOT-323 Outline Dimension

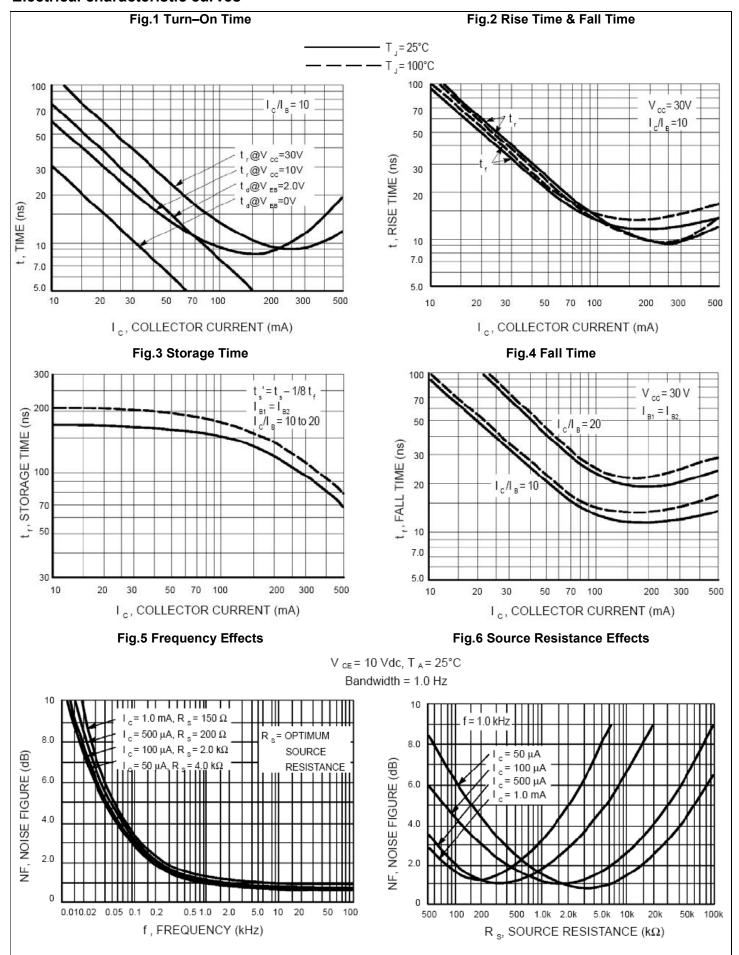


Symbol	Dimension In Millimeters			
Syllibol	Min	Max.		
Α	1.80	2.20		
В	1.15	1.35		
С	0.80	1.00		
D	0.30	0.40		
G	1.20	1.40		
Н	0.00	0.10		
J	0.10	0.25		
K	0.425 REF			
L	0.650 BSC			
N	0.700 REF			
S	2.00 2.40			

Device Marking:

Device P/N	Marking code
MMST4401	2X

Electrical characteristic curves



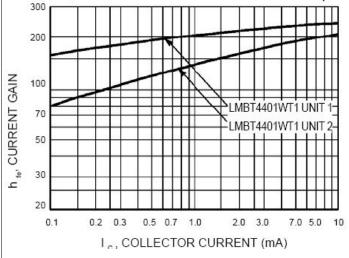
Electrical characteristic curves

Fig.7 Current Gain

Fig.8 Input Admittance

 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_{A} = 25^{\circ}\text{C})$

This group of graphs illustrates the relationship between h fe and other "h" parameters for this series of ransistors. To obtain these curves, a high–gain and a low–gain unit were selected from the LMBT4401WT1G lines, and the same units were used to develop the correspondingly numbered curves on each graph.



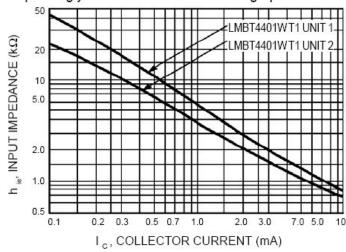
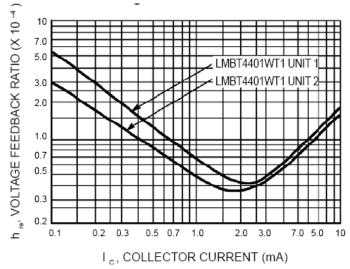


Fig.9 Voltage Feedback Ratio

Fig.10 Output Impedance



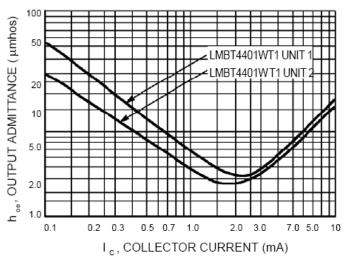
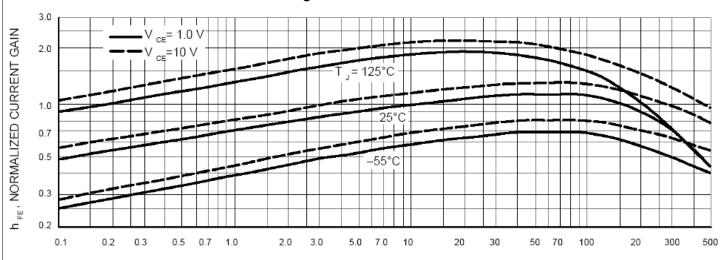
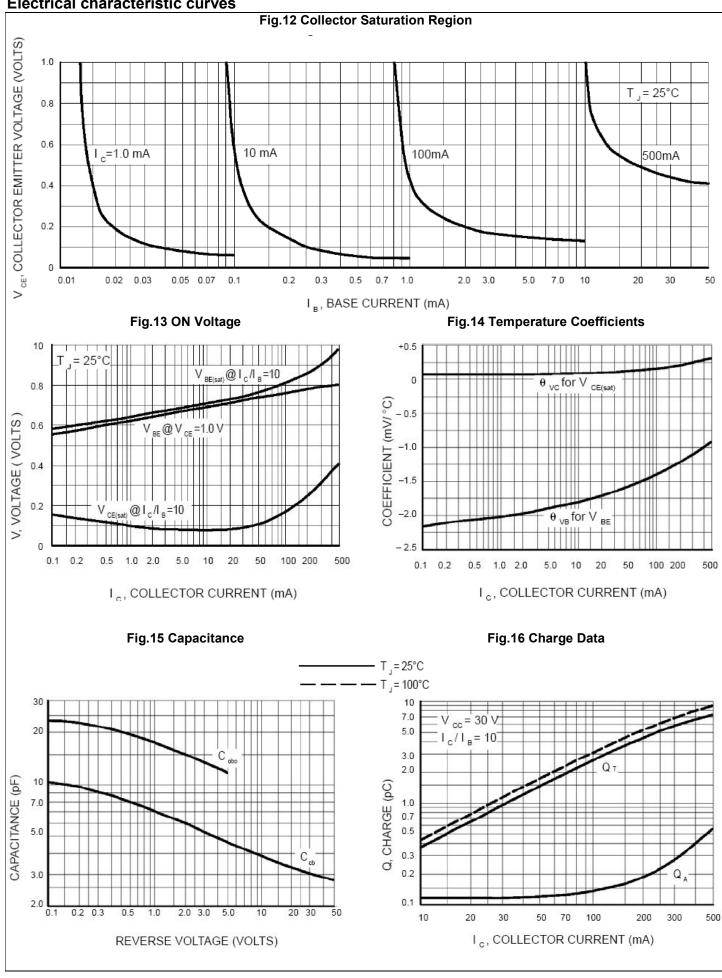


Fig.11 DC Current Gain



Electrical characteristic curves





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New Marking Rule Notification

Range: In order to have well management in process control, the new marking rule is applied to small signal device including Switching Diode, Transistor and Schottky Diode.

Package: SOT-23 / SOT-323 / SOT-523

